

SAMTM Data Sheet SAM-1040-15-500fs-x, λ = 1040 nm

Laser wavelength $\lambda = 1040 \text{ nm}$

High reflection band $\lambda = 980 ... 1070 \text{ nm}$

Absorbance $A_0 = 15 \%$ Modulation depth $\Delta R = 8 \%$ Non-saturable loss $A_{ns} = 7 \%$

Saturation fluence $\Phi_{sat} = 50 \,\mu\text{J/cm}^2$

Relaxation time constant $\tau \sim 500 \text{ fs}$

Damage threshold $\Phi = 1.8 \text{ mJ/cm}^2$

Chip area 4.0 mm x 4.0 mm; other dimensions on request

Chip thickness 450 µm

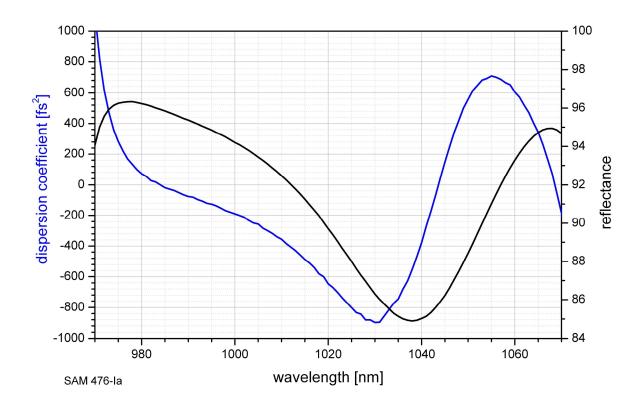
Protection the SAM is protected with a dielectric front layer

Mounting option **x** denotes the type of mounting as follows:

x = 0 unmounted

 $x = 12.7 \, \mathrm{g}$ glued on a gold plated Cu-cylinder with 12.7 mm \varnothing $x = 25.4 \, \mathrm{g}$ glued on a gold plated Cu-cylinder with 25.4 mm \varnothing $x = 12.7 \, \mathrm{s}$ soldered on a gold plated Cu-cylinder with 12.7 mm \varnothing $x = 25.4 \, \mathrm{s}$ soldered on a gold plated Cu-cylinder with 25.4 mm \varnothing $x = 25.0 \, \mathrm{w}$ soldered on a water cooled Cu-cylinder with 25.0 mm \varnothing x = FCmounted on a 1 m monomode fiber cable with FC connector

Low intensity spectral reflectance and dispersion coefficient D₂





Group Delay Dispersion (GDD)

Dispersion coefficient
$$D_2(\omega)=\frac{\partial^2\varphi}{\partial\omega^2}$$
 with φ - reflected phase
$$\omega=2\pi\frac{c}{\lambda} \ \ \text{- angular frequency}$$